

CBT3253

Dual 1-of-4 FET multiplexer/demultiplexer

Rev. 2 — 3 December 2014

Product data sheet

1. General description

The CBT3253 is a dual 1-of-4 high-speed TTL-compatible FET multiplexer/demultiplexer. The low ON-resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

The select control inputs (S0, S1) can select the data path, when both output enable inputs (1OE, 2OE) are LOW. When nOE is HIGH, the switch terminals are in the high impedance OFF-state, independent of S0 and S1.

The CBT3253 is characterized for operation from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

2. Features and benefits

- $5\ \Omega$ switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- Latch-up protection exceeds 100 mA per JEDEC standard JESD78 class II level A
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$

3. Ordering information

Table 1. Ordering information

Type number	Temperature range	Package		
		Name	Description	Version
CBT3253D	$-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
CBT3253DB	$-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
CBT3253DS	$-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$	SSOP16 ^[1]	plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm	SOT519-1
CBT3253PW	$-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

[1] Also known as QSOP16.



4. Functional diagram

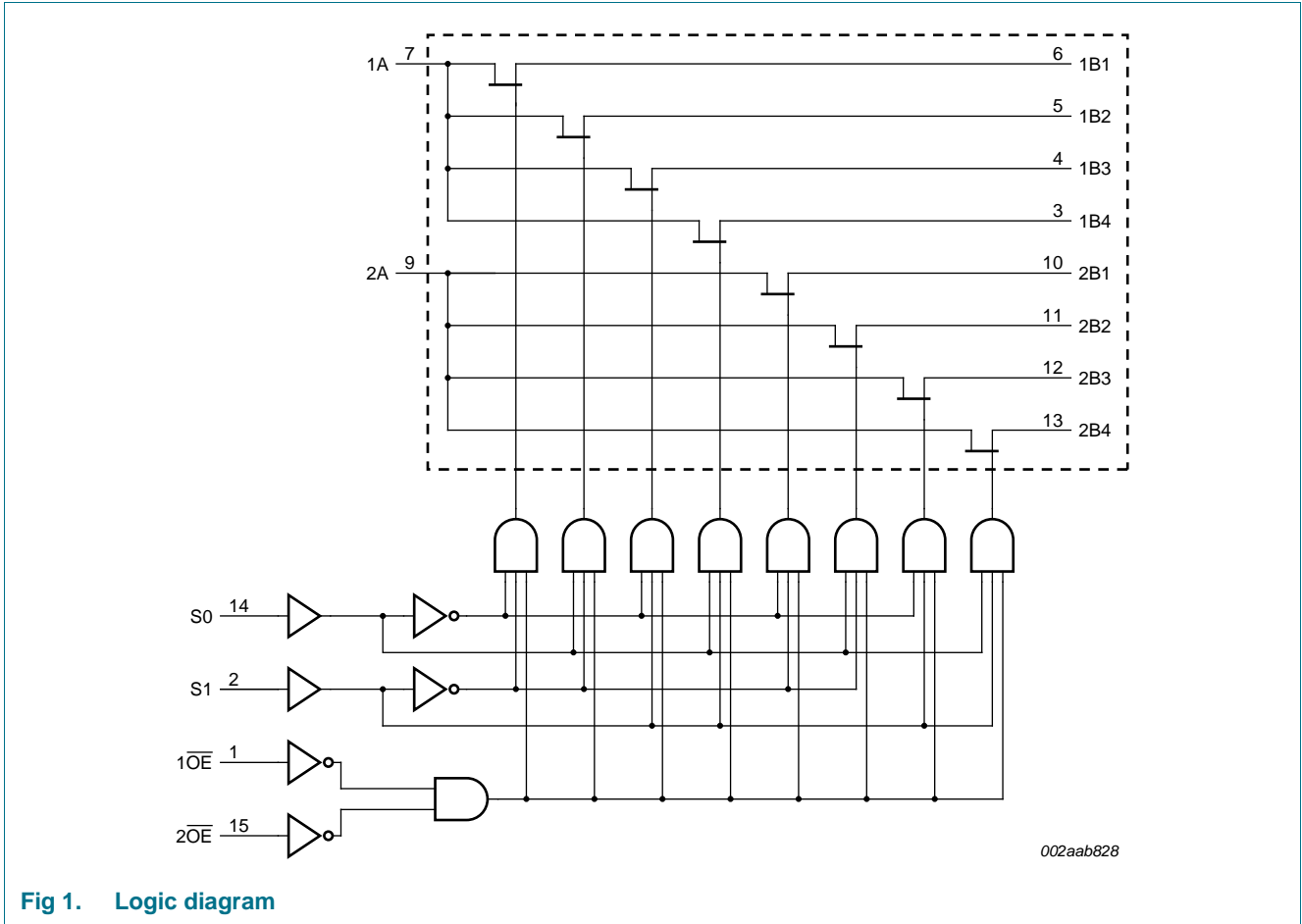
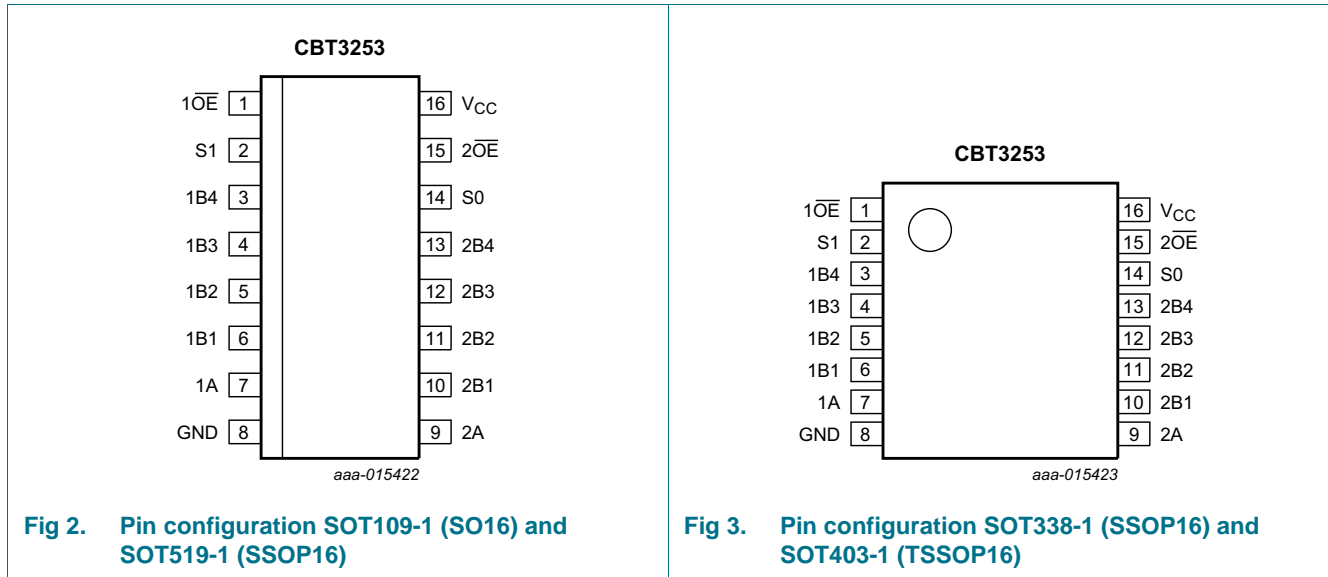


Fig 1. Logic diagram

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1OE, 2OE	1, 15	output enable (active LOW)
S1, S0	2, 14	select control input
1B4, 1B3, 1B2, 1B1	3, 4, 5, 6	1B outputs/inputs
1A	7	1A input/output
GND	8	ground (0 V)
2A	9	2A input/output
2B1, 2B2, 2B3, 2B4	10, 11, 12, 13	2B outputs/inputs
VCC	16	positive supply voltage

6. Functional description

Table 3. Function selection

H = HIGH voltage level; L = LOW voltage level; X = Don't care.

Inputs				Switch
1OE	2OE	S1	S0	
X	H	X	X	disconnect 1A to 1Bn and 2A to 2Bn
H	X	X	X	disconnect 1A to 1Bn and 2A to 2Bn
L	L	L	L	1A to 1B1 and 2A to 2B1
L	L	L	H	1A to 1B2 and 2A to 2B2
L	L	H	L	1A to 1B3 and 2A to 2B3
L	L	H	H	1A to 1B4 and 2A to 2B4

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V _{CC}	supply voltage		-0.5	+7.0	V	
V _I	input voltage		[1] -0.5	+7.0	V	
I _{SW}	switch current	continuous current through each switch	-	128	mA	
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA	
T _{stg}	storage temperature		-65	+150	°C	
P _{tot}	total power dissipation	T _{amb} = -40 °C to +85 °C				
		SO16 package	[2]	-	500	mW
		SSOP16 package	[3]	-	500	mW
		TSSOP16 package	[3]	-	500	mW

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] For SSOP16 and TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 70 °C.

8. Recommended operating conditions

Table 5. Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		4.5	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	V
V _{IL}	LOW-level input voltage		-	0.8	V
T _{amb}	ambient temperature	operating in free-air	-40	+85	°C

9. Static characteristics

Table 6. Static characteristics

$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

Symbol	Parameter	Conditions	Min	Typ ^[1]	Max	Unit
V_{IK}	input clamping voltage	$V_{CC} = 4.5\text{ V}$; $I_I = -18\text{ mA}$	-	-	-1.2	V
V_{pass}	pass voltage	$V_I = V_{CC} = 5.0\text{ V}$; $I_O = -100\text{ }\mu\text{A}$	3.6	3.9	4.2	V
I_I	input leakage current	$V_{CC} = 5.5\text{ V}$; $V_I = \text{GND}$ or 5.5 V	-	-	± 1	μA
I_{CC}	supply current	$V_{CC} = 5.5\text{ V}$; $I_O = 0\text{ mA}$; $V_I = V_{CC}$ or GND	-	-	3	μA
ΔI_{CC}	additional supply current	per input; $V_{CC} = 5.5\text{ V}$; one input at [2] 3.4 V , other inputs at V_{CC} or GND	-	-	2.5	mA
C_I	input capacitance	control pins; $V_I = 3\text{ V}$ or 0 V	-	4.5	-	pF
$C_{io(off)}$	off-state input/output capacitance	A port; $V_O = 3\text{ V}$ or 0 V ; $\overline{nOE} = V_{CC}$	-	11.4	-	pF
		B port; $V_O = 3\text{ V}$ or 0 V ; $\overline{nOE} = V_{CC}$	-	3.8	-	pF
$C_{io(on)}$	on-state input/output capacitance	A port and B port	-	18.6	-	pF
R_{ON}	ON resistance	$V_{CC} = 4.5\text{ V}$ [3]				
		$V_I = 0\text{ V}$; $I_I = 64\text{ mA}$	-	5	7	Ω
		$V_I = 0\text{ V}$; $I_I = 30\text{ mA}$	-	5	7	Ω
		$V_I = 2.4\text{ V}$; $I_I = -15\text{ mA}$	-	10	15	Ω

[1] All typical values are measured at $V_{CC} = 5\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$.

[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND .

[3] Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. The lowest voltage of the two (A or B) terminals determines the ON resistance.

10. Dynamic characteristics

Table 7. Dynamic characteristics

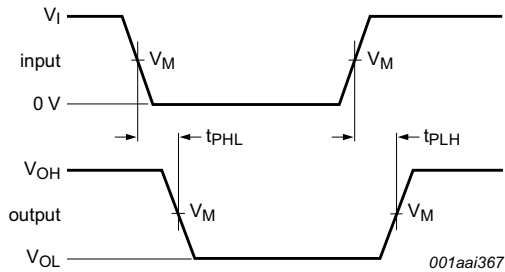
$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$; $V_{CC} = 4.5\text{ V}$ to 5.5 V ; for test circuit, see [Figure 6](#).

Symbol	Parameter	Conditions	Min	Max	Unit
t_{pd}	propagation delay	nA to nBn or nBn to nA; see Figure 4 [1][2]	-	0.25	ns
		Sn to nA; see Figure 4 [1][2]	1.2	6.2	ns
t_{en}	enable time	Sn to nBn; see Figure 5 [2]	1.3	6.3	ns
		\overline{nOE} to nA or nBn; see Figure 5 [2]	1.4	6.4	ns
t_{dis}	disable time	Sn to nBn; see Figure 5 [2]	1.1	7.2	ns
		\overline{nOE} to nA or nBn; see Figure 5 [2]	1.0	7	ns

[1] This parameter is warranted but not production tested. The propagation delay is based on the RC time constant of the typical ON resistance of the switch and a load capacitance, when driven by an ideal voltage source (zero output impedance).

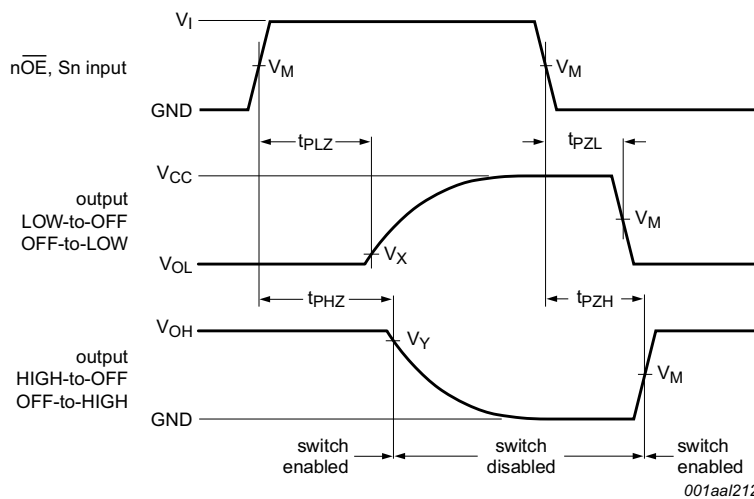
[2] t_{PLH} and t_{PHL} are the same as t_{pd} .
 t_{PZL} and t_{PZH} are the same as t_{en} .
 t_{PLZ} and t_{PHZ} are the same as t_{dis} .

11. AC waveforms



Measurement points are given in [Table 8](#).
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 4. The input (nA, nBn) to output (nBn, nA) or input (Sn) to output (nA) propagation delay times



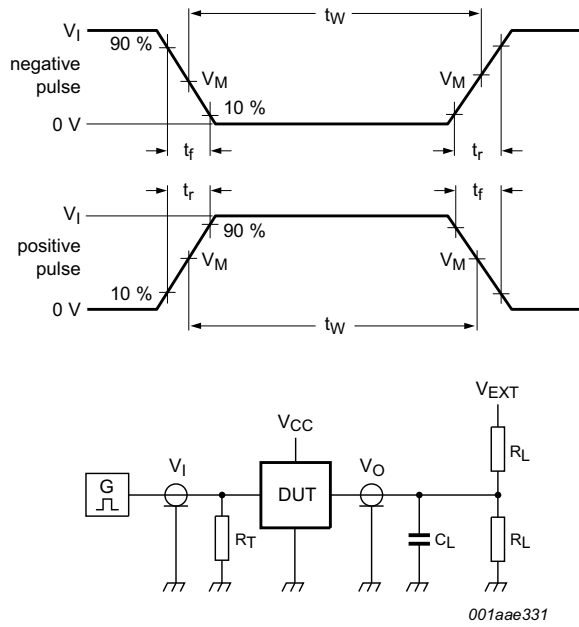
Measurement points are given in [Table 8](#).
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. Enable and disable times

Table 8. Measurement points

Supply voltage	Input		Output		
V_{CC}	V_I	V_M	V_M	V_X	V_Y
4.5 V to 5.5 V	GND to 3.0 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$

12. Test information



Test data is given in [Table 9](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

Fig 6. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load		V_{EXT}		
V_{CC}	V_I	t_r, t_f	C_L	R_L	t_{PLH}, t_{PHL}	t_{PLZ}, t_{PZL}	t_{PHZ}, t_{PZH}
4.5 V to 5.5 V	GND to 3.0 V	≤ 2.5 ns	50 pF	500 Ω	open	7.0 V	open

13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

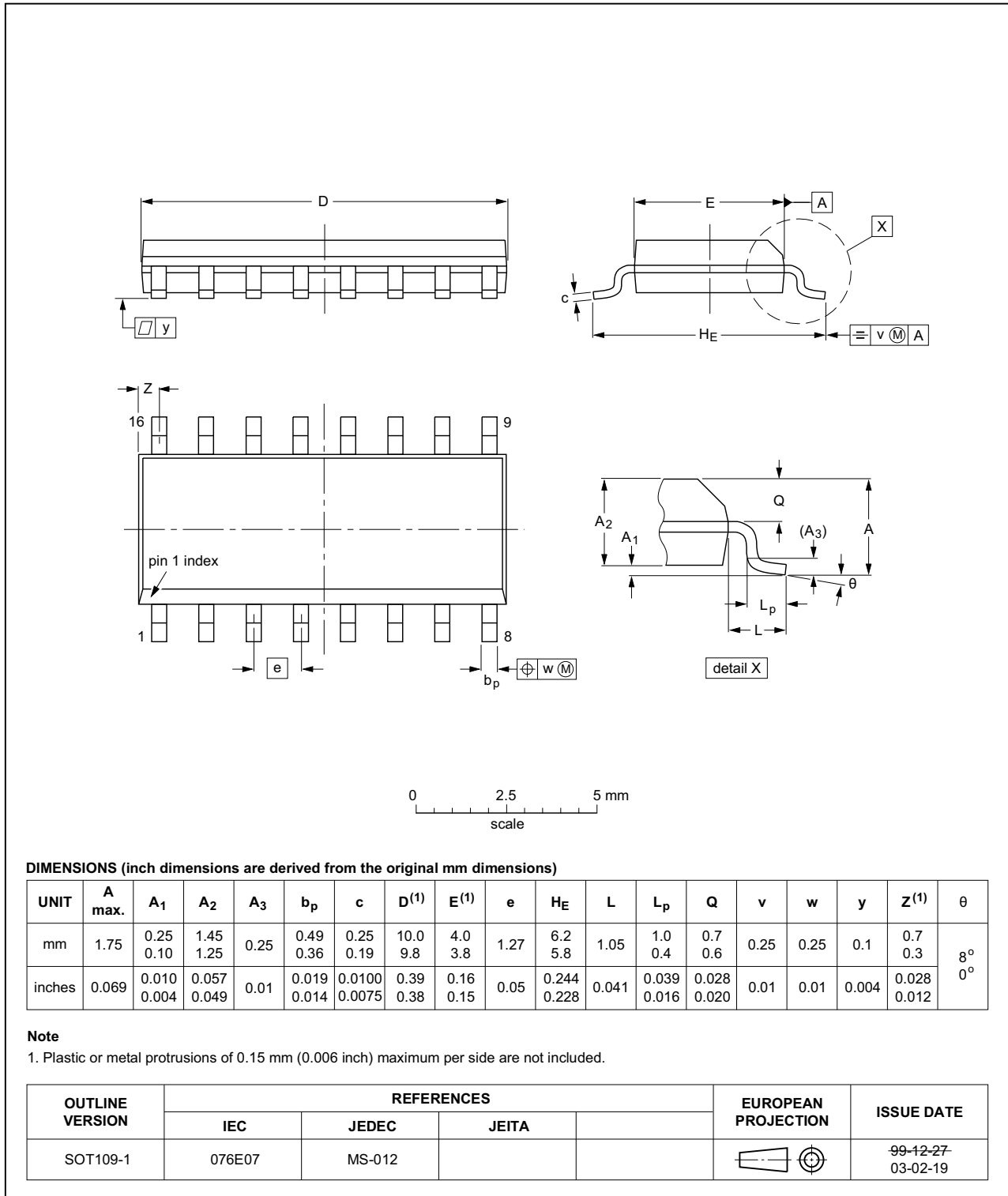


Fig 7. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

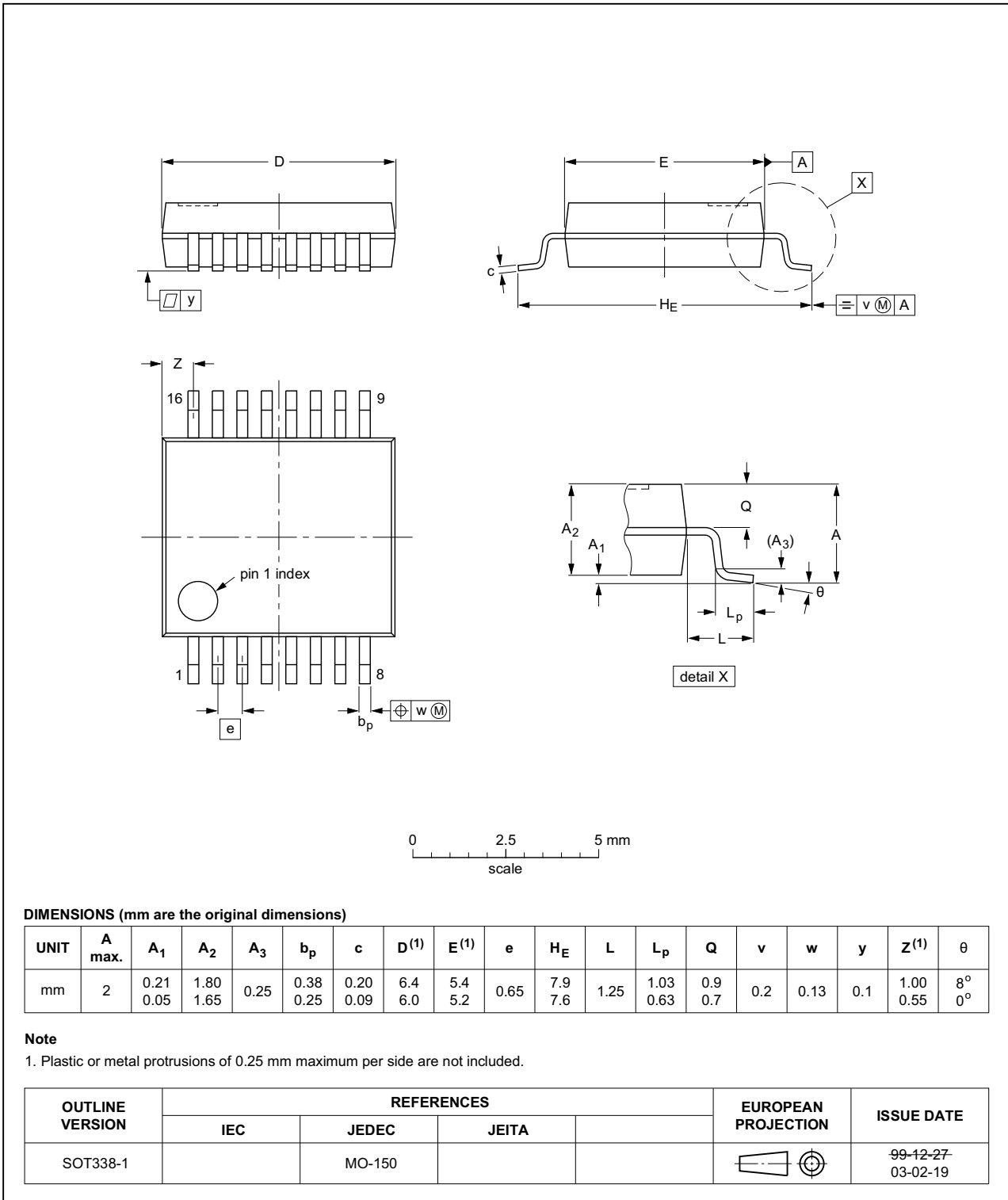


Fig 8. Package outline SOT338-1 (SSOP16)

SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

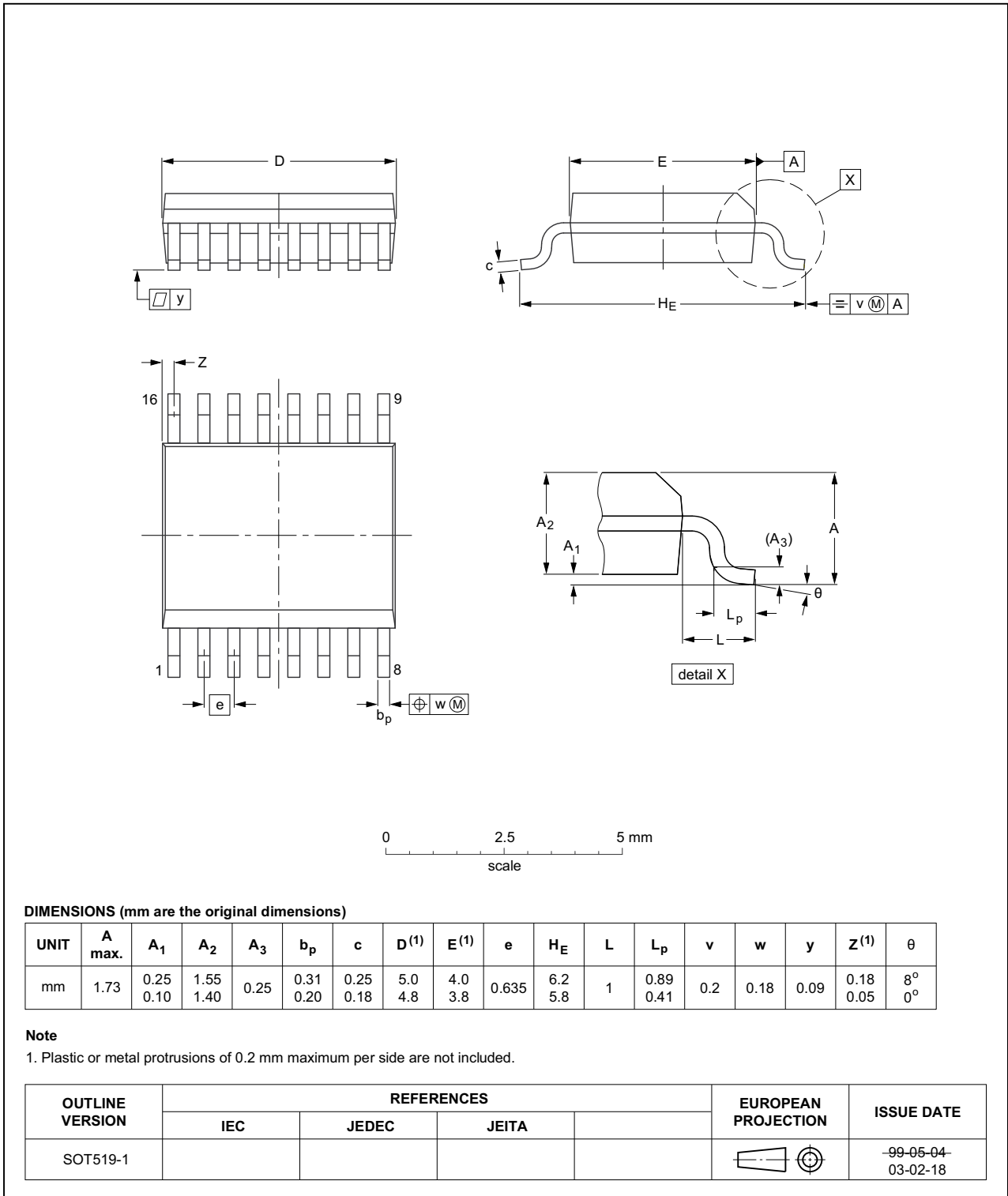


Fig 9. Package outline SOT519-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

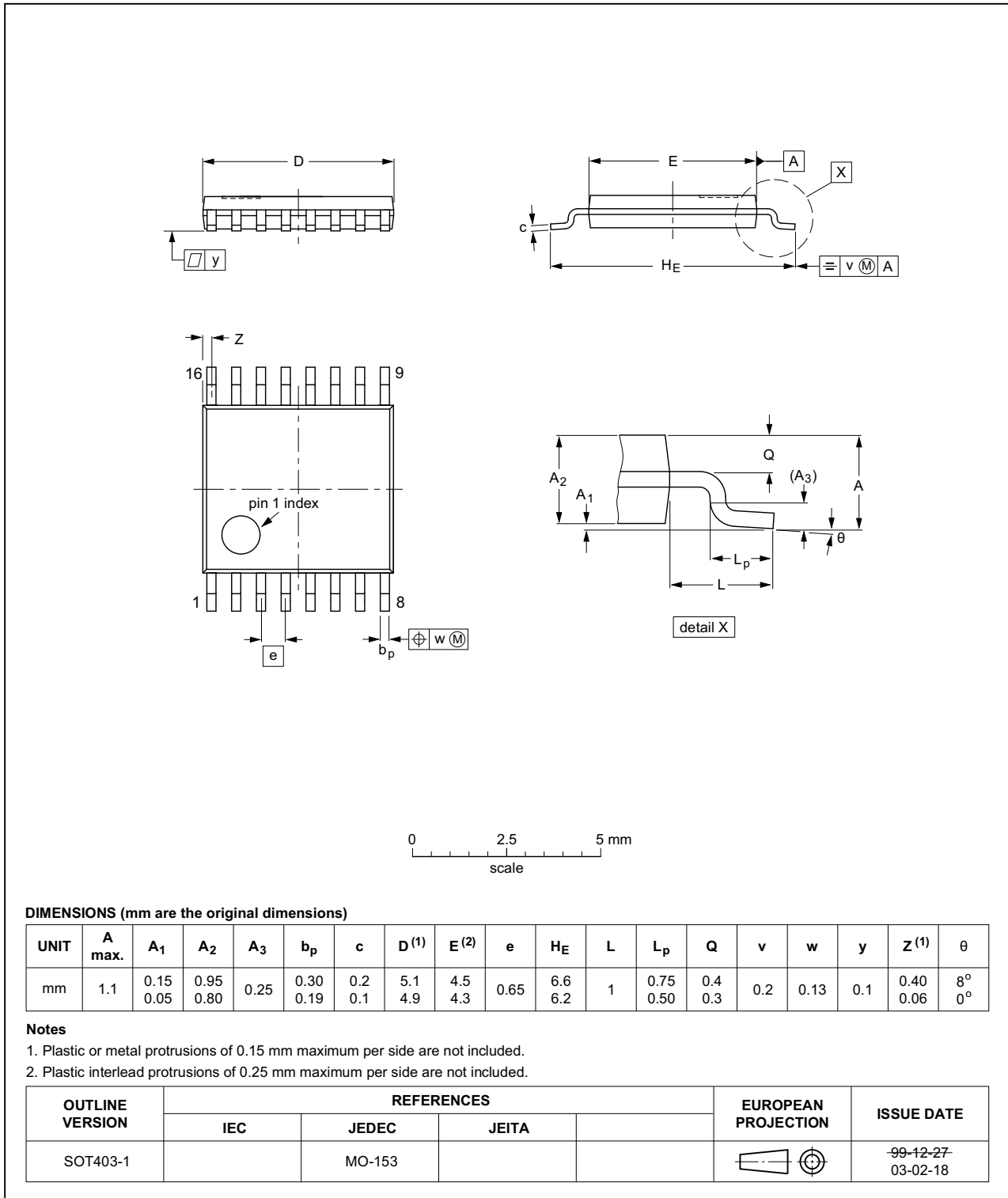


Fig 10. Package outline SOT403-1 (TSSOP16)

14. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CBT3253 v.2	20141203	Product data sheet	-	CBT3253 v.1
Modifications:	<ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Section 1 "General description": text changed to align with the function of the device. Figure 1 "Logic diagram": schematic changed. Table 3 "Function selection": switch description changed to align with the function of the device. Table 6 "Static characteristics": <ul style="list-style-type: none"> $C_{iO(off)}$, A port: changed typical value from 23.5 pF to 11.4 pF $C_{iO(off)}$, B port: changed typical value from 6.5 pF to 3.8 pF added $C_{iO(on)}$ specification Table 6 "Static characteristics": values for pass voltage modified. 			
CBT3253 v.1	20021104	Product data sheet	-	-

16. Legal information

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Document status ^{[1][2]}	Product status ^[3]	Definition
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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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